

## **Transient Voltage Suppressors for ESD Protection**

### **General Description**

The LESD3Z5.0CMT1G is designed to protect voltage sensitive components from ESD and transient voltage events. Excellent clamping capability, low leakage, and fast response time, make these parts ideal for ESD protection on designs where board space is at a premium.

## **Applications**

- Cellular phones
- Portable devices
- Digital cameras
- Power supplies
- S- Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

### **Features**

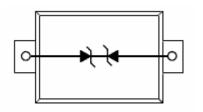
- Small Body Outline Dimensions
- Low Body Height
- Peak Power up to 200 Watts @ 8 x 20 \_s
  Pulse
- Low Leakage current
- Response Time is Typically < 1 ns
- ESD Rating of Class 3 (> 16 kV) per Human Body Model
- IEC61000-4-2 Level 4 ESD Protection
- IEC61000-4-4 Level 4 EFT Protection

## Absolute Ratings (T<sub>amb</sub>=25°C)

Symbol	Parameter	Value	Units	
P <sub>PP</sub>	Peak Pulse Power (t <sub>p</sub> = 8/20 μ s)	200	W	
T <sub>L</sub>	Maximum lead temperature for soldering during 10s	260	°C	
T <sub>stg</sub>	Storage Temperature Range	-55 to +155	°C	
T <sub>op</sub>	Operating Temperature Range	-40 to +125	°C	
Tj	Maximum junction temperature		150	°C
	IEC61000-4-2 (ESD)	air discharge contact discharge	±15 ±8	KV
	IEC61000-4-4 (EFT)		40	Α
	ESD Voltage Per l	Human Body Model	16	KV

## LESD3Z5.0CMT1G S-LESD3Z5.0CMT1G





#### **ORDERING INFORMATION**

Device	Marking	Shipping
LESD3Z5.0CMT1G S-LESD3Z5.0CMT1G	3М	3000/Tape & Reel

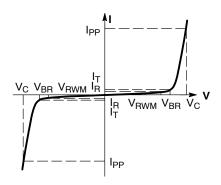


# LESD3Z5.0CMT1G,S-LESD3Z5.0CMT1G

### **Electrical Parameter**

(T<sub>A</sub> = 25°C unless otherwise noted)

Symbol	Parameter					
I <sub>PP</sub>	Maximum Reverse Peak Pulse Current					
V <sub>C</sub>	V <sub>C</sub> Clamping Voltage @ I <sub>PP</sub>					
V <sub>RWM</sub>	Working Peak Reverse Voltage					
I <sub>R</sub>	Maximum Reverse Leakage Current @ V <sub>RWM</sub>					
$V_{BR}$	Breakdown Voltage @ I <sub>T</sub>					
I <sub>T</sub>	Test Current					
P <sub>pk</sub>	Peak Power Dissipation					
С	Capacitance @ V <sub>R</sub> = 0 and f = 1.0 MHz					



## **Electrical Characteristics** Ratings at 25°C ambient temperature unless otherwise specified.VF = 0.9V at IF = 10mA

Device	V <sub>RWM</sub> (V)	I <sub>R</sub> (uA) @ V <sub>RWM</sub>	V <sub>BR</sub> (V)@ I <sub>T</sub> (Note 1)	Ι <sub>τ</sub>	V <sub>C</sub> (V) @ I <sub>PP</sub> =5 A*	V <sub>C</sub> (V) @ Max I <sub>PP</sub> *	I <sub>PP</sub> (A)*	P <sub>PK</sub> (W)*	C (pF)
	Max	Max	Min	mA	Тур	Max	Max	Max	Тур
LESD3Z5.0CMT1G	5.0	1	5.6	1.0	11.6	18.6	9.4	174	25

<sup>\*</sup>Surge current waveform per Figure 1.

1.  $V_{BR}$  is measured with a pluse test current  $I_T$  at an ambient temperature of 25  $^\circ\!\!\!\!$  C .

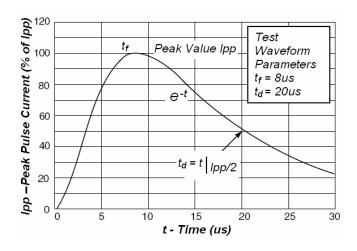


Fig1. Pulse Waveform



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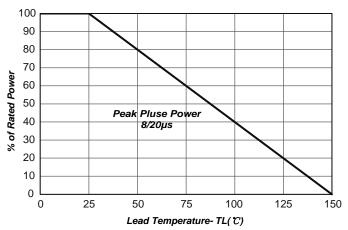


Fig2.Power Derating

### **Application Note**

Electrostatic discharge (ESD) is a major cause of failure in electronic systems. Transient Voltage Suppressors (TVS) are an ideal choice for ESD protection. They are capable of clamping the incoming transient to a low enough level such that damage to the protected semiconductor is prevented.

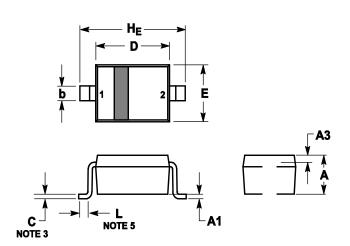
Surface mount TVS offers the best choice for minimal lead inductance. They serve as parallel protection elements, connected between the signal lines to ground. As the transient rises above the operating voltage of the device, the TVS becomes a low impedance path diverting the transient current to ground. The LESD3Z5.0CMT1G is the ideal board evel protection of ESD sensitive semiconductor components.

The tiny SOD-323 package allows design flexibility in the design of high density boards where the space saving is at a premium. This enables to shorten the routing and contributes to hardening against ESD.



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### **OUTLINE AND DIMENSIONS**

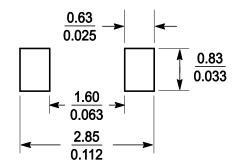


### Notes:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETERS.
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.

	MILLIMETERS			MILLIMETERS INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.8	0.9	1	0.031	0.035	0.04
A1	0	0.05	0.1	0	0.002	0.004
A3	0.15REF			REF 0.006REF		
b	0.25	0.32	0.4	0.01	0.012	0.016
С	0.089	0.12	0.177	0.003	0.005	0.007
D	1.6	1.7	1.8	0.062	0.066	0.07
Е	1.15	1.25	1.35	0.045	0.049	0.053
L	0.08			0.003		
H <sub>E</sub>	2.3	2.5	2.7	0.09	0.098	0.105

### **SOLDERING FOOTPRINT**



## 单击下面可查看定价,库存,交付和生命周期等信息

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